

Power Matters.™

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HS2907A (#18662)

Overview

Electrical Rating	Symbol	Min	Typ	Max	Unit
DC Current Gain	HFE	75.00		300.00	

Maximum Electrical Rating	Symbol	Min	Typ	Max	Unit
Breakdown Voltage, Collector-Base (Emitter Open)	V _{BR(CBO)}			60.00	V
Collector Current (dc)	I _C			0.60	A
Collector-Emitter Voltage (Base Open)	V _{CEO}			60.00	V
Emitter-Base Voltage (Collector Open)	V _{EBO}			3.00	V
Power Dissipation, Total	P _T			0.40	W

This part can be found in the following product categories:

- Discretes > Transistors > BJT(BiPolar Junction Transistor) > PNP Transistor
- Non-Radiation Hardened Devices > Transistors > BJT(BiPolar Junction Transistor) > PNP Transistor

Related Links

- Technical support
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